



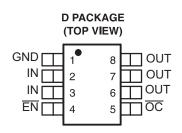
SINGLE-CHANNEL 100 mA POWER SWITCH

FEATURES

www.ti.com

- 100-mA Continuous Current
- 600-mΩ High-Side MOSFET
- Thermal and Short-Circuit Protection
- Operating Range: 2.7 V to 5.5 V
- 0.6-ms Typical Rise Time
- Undervoltage Lockout
- Deglitched Fault Report (OC)
- 43 µA Quiescent Supply Current
- 1-µA Maximum Standby Supply Current

- SOIC-8 Package
- Ambient Temperature Range: -40°C to 85°C
- 2 µS Response Time to Short Circuit



DESCRIPTION

The TPS2049 power-distribution switch is intended for applications where heavy capacitive loads and short circuits are likely to be encountered. This device incorporates a 600-m Ω N-channel MOSFET power switch for power-distribution systems that require only one power distribution path. The switch is controlled by a logic enable input. Gate drive is provided by an internal charge pump designed to control the power-switch rise times and fall times to minimize current surges during switching. The charge pump requires no external components and allows operation from supplies as low as 2.7V.

When the output load exceeds the current-limit threshold or a short is present, the device limits the output current to a safe level by switching into a constant-current mode, pulling the overcurrent (\overline{OC}) logic output low. When continuous heavy overloads and short circuits increase the power dissipation in the switch, causing the junction temperature to rise, a thermal protection circuit shuts off the switch to prevent damage. Recovery from a thermal shutdown is automatic once the device has cooled sufficiently. Internal circuitry ensures the switch remains off until valid input voltage is present. This power-distribution switch is designed to set current limit at 150mA typically.

GENERAL SWITCH CATALOG									
33 mΩ, Single	80 mΩ, Single	80 mΩ, Dual	80 mΩ, Dual	80 m Ω , Triple	80 m Ω , Quad	80 mΩ, Quad			
TPS201xA 0.2 A to 2 A TPS202x 0.2 A to 2 A TPS203x 0.2 A to 2 A	TPS2014 600 mA TPS2015 1A TPS2041B 500 mA TPS2051B 500 mA TPS2045A 250 mA TPS2045A 250 mA TPS2055A 250 mA TPS2065 1A TPS2065 1A TPS2068 1.5 A TPS2069 1.5 A	TPS2042B 500 mA TPS2052B 500 mA TPS2056B 500 mA TPS2056 250 mA TPS2056 1A TPS2066 1A TPS2066 1A TPS2060 1.5 A TPS2064 1.5 A	TPS2080 500 mA TPS2081 500 mA TPS2082 500 mA TPS2092 250 mA TPS2091 250 mA TPS2092 250 mA	TPS2043B 500 mA TPS2053B 500 mA TPS2053B 500 mA TPS2057A 250 mA TPS2057A 250 mA TPS2063 1A TPS2067 1A	TPS2044B 500 mA TPS2054B 500 mA TPS2058 250 mA TPS2058 250 mA	TPS2085 500 mA TPS2086 500 mA TPS2086 500 mA TPS2087 500 mA TPS2095 250 mA TPS2096 250 mA TPS2097 250 mA			



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



www.ti.com



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

AVAILABLE OPTION AND ORDERING INFORMATION⁽¹⁾

T _A	ENABLE	RECOMMENDED MAXIMUM CONTINUOUS LOAD CURRENT (mA)	TYPICAL SHORT-CIRCUIT CURRENT LIMIT AT 25°C (mA)	NUMBER OF SWITCHES	SOIC (D)
–40°C to 85°C	Active low	100	150	Single	TPS2049D ⁽²⁾

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(2) The package is available taped and reeled. Add an R suffix to device types (e.g., TPS2042BDR)

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted⁽¹⁾

			VALUE	UNIT	
V _{I(IN)}	Input voltage range (2)		-0.3 to 6	V	
V _{O(OUT)}	Output voltage range (2)	-0.3 to 6	V		
V _{I(EN)}	Input voltage range	-0.3 to 6	V		
V _{I(OC)}	Voltage range	-0.3 to 6	V		
I _{O(OUT)}	Continuous output current	Internally lim	Internally limited		
	Continuous total power dissipati	See Dissipation Ra	See Dissipation Rating Table		
TJ	Operating virtual junction tempe	rature range	-40 to 125	°C	
T _{stg}	Storage temperature range		-65 to 150	°C	
	Lead temperature soldering 1,6	mm (1/16 inch) from case for 10 seconds	260	°C	
	Electrostatic discharge (ESD)	Human body model MIL-STD-883C	2	kV	
	protection	Charge device model (CDM)	500	V	

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to GND.

DISSIPATING RATING TABLE

PACKAGE	T _A ≤ 25°C	DERATING FACTOR	T _A = 70°C	T _A = 85°C
	POWER RATING	ABOVE T _A = 25°C	POWER RATING	POWER RATING
D-8	585.82 mW	5.8582 mW/C	322.20 mW	234.32 mW

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
V _{I(IN)}	Input voltage	2.7	5.5	V
V _{I(EN)}	Input voltage	0	5.5	V
I _{O(OUT)}	Continuous output current	0	100	mA
TJ	Operating virtual junction temperature	-40	125	°C



ELECTRICAL CHARACTERISTICS

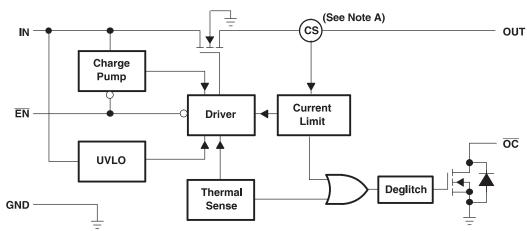
over recommended operating junction temperature range, $V_{I(IN)} = 5.5 \text{ V}$, $I_O = 90 \text{ mA}$, $V_{I(EN)} = 0 \text{ V}$ (unless otherwise noted)

	PARAMETER	-	MIN	TYP	MAX	UNIT		
POWEF	R SWITCH	·						
r _{DS(on)}	Static drain-source on-state resistance, 5-V operation and 2.7-V operation	$V_{I(IN)} = 2.7 V \text{ or } 5.5 V,$	I _O = 90 A,	–40°C < T _J < 125°C		400	650	mΩ
t _r	Rise time, output	V _{I(IN)} = 2.7 V	$C_{L} = 1 F,$	$R_L = 50~\Omega,~T_J = 25^\circ C$		0.1	0.4	ms
t _f	Fall time, output	V _{I(IN)} = 2.7 V	$C_L = 1 F$,	$R_L = 50~\Omega,~T_J = 25^\circ C$	0.03		0.3	ms
ENABL	e input en							
V _{IH}	High-level input voltage	$2.7 \text{ V} \leq \text{V}_{I(IN)} \leq 5.5 \text{ V}$			2			V
V _{IL}	Low-level input voltage	$2.7 \text{ V} \leq \text{V}_{I(IN)} \leq 5.5 \text{ V}$					0.8	V
l _l	Input current	$V_{I(EN)} = 0 V \text{ or } V_{I(EN)} = V$	V _{I(IN)}		-0.5		0.5	μΑ
t _{on}	Turnon time	$C_L = 1 \ \mu F, R_L = 50 \ \Omega, T$	ſ _J = 25°C				1	ms
t _{off}	Turnoff time	$C_L = 1 \text{ F}, \text{ R}_L = 50 \Omega, \text{ T}_J$	= 25°C				1	ms
CURRE	ENT LIMIT							
I _{OS}	Short-circuit output current		$V_{I(IN)} = 5 \text{ V}$, OUT connected to GND, Device enabled into short-circuit, $10^{\circ}C < T_{.1} < 40^{\circ}C$					
I _{OC_trip}	Overcurrent trip threshold	$10^{\circ}C < T_{J} < 40^{\circ}C, 100$			325	mA		
	Short-circuit response time			2		μs		
SUPPL	Y CURRENT							
Supply	current, low-level output	No load on OUT	V _{I(EN)} = 5.5 V	$T_{J} = 25^{\circ}C$ $-40C \le T_{J} \le 125^{\circ}C$		0.5 0.5	1 5	μA
		No load on OUT	V _{I(EN)} = 0 V	$T_{\rm J} = 25^{\circ}{\rm C}$		43	60	
Supply	current, high-level output			-40C ≤ T _J ≤ 125°C		43	70	μA
Leakage	e current	OUT connected to ground	V _{I(EN)} = 5.5 V,	$-40C \le T_J \le 125^{\circ}C$		1	10	μA
Reverse	e leakage current	IN = ground	$V_{I(OUT)} = 5.5 V,$ $V_{I(EN)} = 0 V$	$T_J = 25^{\circ}C$		0		μA
UNDER	VOLTAGE LOCKOUT			- H				
IN	Low-level input voltage				2		2.5	V
IN	Hysteresis	T _J = 25C				75		mV
OVERC	URRENT OC							
V _{OL(OC)}	Output low voltage	I _{O(OC)} = 5 mA					0.4	V
Off-state current $V_{O(OC)} = 5 \text{ V or } 3.3 \text{ V}$							1	μA
OC deg	litch	OC assertion or de-ass	4	8	15	ms		
THERM	IAL SHUTDOWN ⁽²⁾							
Therma	I shutdown threshold				135			°C
Recove	ry from thermal shutdown				125			°C
Hystere	sis			10		°C		

(1) Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.

(2) The thermal shutdown only reacts under overcurrent conditions.





FUNCTIONAL BLOCK DIAGRAM

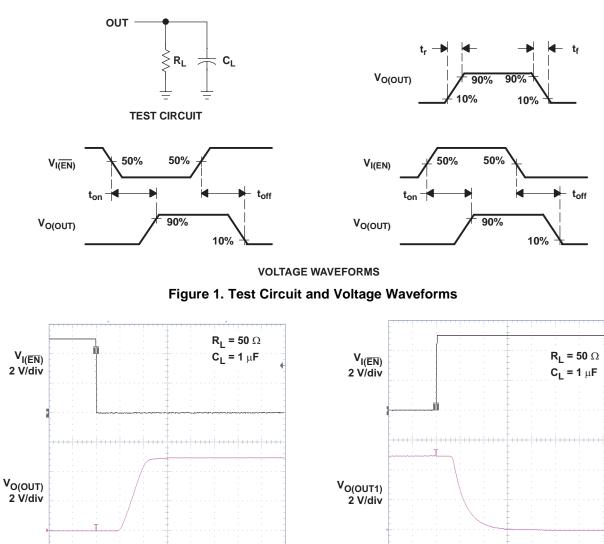
Note A: Current sense

TERMINAL FUNCTIONS

TEF	TERMINAL		DESCRIPTION					
NAME	NO.	I/O	DESCRIPTION					
EN1	4	I	Enable input, logic low turns on power switch					
GND	1	I	Ground					
IN	2, 3	I	Input voltage					
<u> 00</u>	5	0	Overcurrent, report, active-low, open-drain output					
OUT	6, 7, 8	0	Power-switch output					



PARAMETER MEASUREMENT INFORMATION



t - Time - 100 $\mu s/div$ Figure 2. Turnon Delay and Rise Time With 1- μF Load

Figure 3. Turnoff Delay and Fall Time With 1- μF Load

t - Time - 100 μs/div

SLVS713A-OCTOBER 2006-REVISED SEPTEMBER 2007

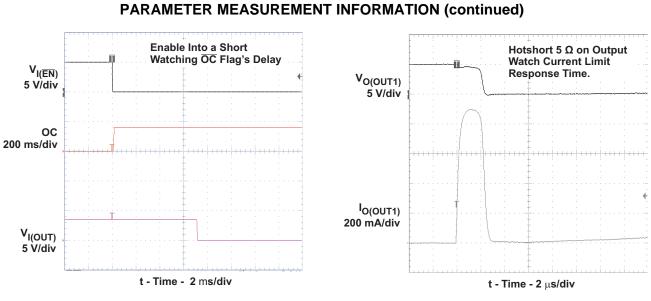


Figure 4. Device Enabled Into a Short





APPLICATION INFORMATION

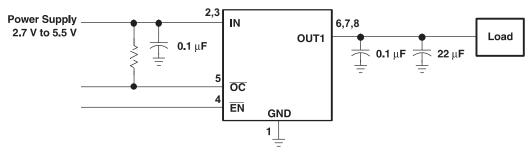


Figure 6. Typical Application

POWER-SUPPLY CONSIDERATIONS

A $0.01-\mu F$ to $0.1-\mu F$ ceramic bypass capacitor between IN and GND, close to the device, is recommended. Placing a high-value electrolytic capacitor on the output pin(s) is recommended when the output load is heavy. This precaution reduces power-supply transients that may cause ringing on the input. Additionally, bypassing the output with a $0.01-\mu F$ to $0.1-\mu F$ ceramic capacitor improves the immunity of the device to short-circuit transients.

OVERCURRENT

A sense FET is employed to check for overcurrent conditions. Unlike current–sense resistors, sense FETs do not increase the series resistance of the current path. When an overcurrent condition is detected, the device maintains a constant output current and reduces the output voltage accordingly. Complete shutdown occurs only if the fault is present long enough to activate thermal limiting.

Three possible overload conditions can occur. In the first condition, the output has been shorted before the device is enabled or before VI(IN) has been applied (see Figure 6). The TPS2049 senses the short and immediately switches into a constant-current output.

In the second condition, a short or an overload occurs while the device is enabled. At the instant the overload occurs, very high currents may flow for a short period of time before the current-limit circuit can react. After the current-limit circuit has tripped (reached the overcurrent trip threshold) the device switches into constant-current mode.

In the third condition, the load has been gradually increased beyond the recommended operating current. The current is permitted to rise until the current-limit threshold is reached or until the thermal limit of the device is exceeded. The TPS2049 is capable of delivering current up to the current-limit threshold without damaging the device. Once the threshold has been reached, the device switches into its constant-current mode.

OC RESPONSE

The $\overline{\text{OC}}$ open-drain output is asserted (active low) when an overcurrent or overtemperature shutdown condition is encountered after a 10-ms deglitch timeout. The output remains asserted until the overcurrent or overtemperature condition is removed. Connecting a heavy capacitive load to an enabled device can cause a momentary overcurrent condition; however, no false reporting on $\overline{\text{OC}}$ occurs due to the 10-ms deglitch circuit. The TPS2049 is designed to eliminate false overcurrent reporting. The internal overcurrent deglitch eliminates the need for external components to remove unwanted pulses. $\overline{\text{OC}}$ is not deglitched when the switch is turned off due to an overtemperature shutdown.

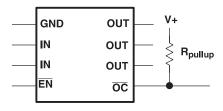


Figure 7. Typical Circuit for the OC Pin



www.ti.com

POWER DISSIPATION AND JUNCTION TEMPERATURE

The low on-resistance on the n-channel MOSFET allows small surface-mount packages to pass large currents. The thermal resistance of these packages are high compared to those of power packages; it is good design practice to check power dissipation and junction temperature. Begin by determining the r_{DS(on)} of the N-channel MOSFET relative to the input voltage and operating temperature. As an initial estimate, use the highest operating ambient temperature of interest. Using this value, the power dissipation per switch can be calculated by:

 $P_D = r_{DS(on)} \times I^2$

Finally, calculate the junction temperature:

 $T_J = P_D \times R_{\Theta JA} + T_A$

Where:

 T_A = Ambient temperature °C

 $R_{\Theta JA}$ = Thermal resistance

 P_D = Total power dissipation based on number of switches being used.

Compare the calculated junction temperature with the initial estimate. If they do not agree within a few degrees, repeat the calculation, using the calculated value as the new estimate. Two or three iterations are generally sufficient to get a reasonable answer.

THERMAL PROTECTION

Thermal protection prevents damage to the IC when heavy-overload or short-circuit faults are present for extended periods of time. The TPS2049 implement a thermal sensing to monitor the operating junction temperature of the power distribution switch. In an overcurrent or short-circuit condition the junction temperature will rise due to excessive power dissipation. Once the die temperature rises to approximately 140°C due to overcurrent conditions, the internal thermal sense circuitry turns the power switch off, thus preventing the power switch from damage. Hysteresis is built into the thermal sense circuit, and after the device has cooled approximately 10°C, the switch turns back on. The switch continues to cycle in this manner until the load fault or input power is removed. The OC open-drain output is asserted (active low) when an overtemperature shutdown or overcurrent occurs.

UNDERVOLTAGE LOCKOUT (UVLO)

An undervoltage lockout ensures that the power switch is in the off state at power up. Whenever the input voltage falls below approximately 2 V, the power switch will be quickly turned off. This facilitates the design of hot-insertion systems where it is not possible to turn off the power switch before input power is removed. The UVLO will also keep the switch from being turned on until the power supply has reached at least 2 V, even if the switch is enabled. Upon reinsertion, the power switch will be turned on, with a controlled rise time to reduce EMI and voltage overshoots.



GENERIC HOT-PLUG APPLICATIONS (see Figure 8)

In many applications it may be necessary to remove modules or pc boards while the main unit is still operating. These are considered hot-plug applications. Such implementations require the control of current surges seen by the main power supply and the card being inserted. The most effective way to control these surges is to limit and slowly ramp the current and voltage being applied to the card, similar to the way in which a power supply normally turns on. Due to the controlled rise times and fall times of the TPS2049, these devices can be used to provide a softer start-up to devices being hot-plugged into a powered system. The UVLO feature of the TPS2049 also ensures the switch will be off after the card has been removed, and the switch will be off during the next insertion. The UVLO feature insures a soft start with a controlled rise time for every insertion of the card or module.

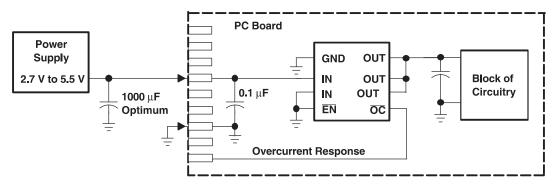


Figure 8. Typical Hot-Plug Implementation

By placing the TPS2049 between the V_{CC} input and the rest of the circuitry, the input power reaches these devices first after insertion. The typical rise time of the switch is approximately 1 ms, providing a slow voltage ramp at the output of the device. This implementation controls system surge currents and provides a hot-plugging mechanism for any device.

DETAILED DESCRIPTION

POWER SWITCH

The power switch is an N-channel MOSFET with a low on-state resistance. Configured as a high-side switch, the power switch prevents current flow from OUT to IN and IN to OUT when disabled. The power switch supplies a minimum current of 90 mA.

CHARGE PUMP

An internal charge pump supplies power to the driver circuit and provides the necessary voltage to pull the gate of the MOSFET above the source. The charge pump operates from input voltages as low as 2.7 V and requires little supply current.

DRIVER

The driver controls the gate voltage of the power switch. To limit large current surges and reduce the associated electromagnetic interference (EMI) produced, the driver incorporates circuitry that controls the rise times and fall times of the output voltage.

ENABLE (EN)

The logic enable pin disables the power switch and the bias for the charge pump, driver, and other circuitry to reduce the supply current. The supply current is reduced to less than 1 μ A when a logic high is present on EN. A logic zero input on EN restores bias to the drive and control circuits and turns the switch on. The enable input is compatible with both TTL and CMOS logic levels.



www.ti.com

OVERCURRENT (OC)

The \overline{OC} open-drain output is asserted (active low) when an overcurrent or overtemperature condition is encountered. The output remains asserted until the overcurrent or overtemperature condition is removed. A 10-ms deglitch circuit prevents the \overline{OC} signal from oscillation or false triggering. If an overtemperature shutdown occurs, the \overline{OC} is asserted instantaneously.

CURRENT SENSE

A sense FET monitors the current supplied to the load. The sense FET measures current more efficiently than conventional resistance methods. When an overload or short circuit is encountered, the current-sense circuitry sends a control signal to the driver. The driver in turn reduces the gate voltage and drives the power FET into its saturation region, which switches the output into a constant-current mode and holds the current constant while varying the voltage on the load.

THERMAL SENSE

The TPS2049 implements a thermal sensing to monitor the operating temperature of the power distribution switch. In an overcurrent or short-circuit condition, the junction temperature rises. When the die temperature rises to approximately 140°C due to overcurrent conditions, the internal thermal sense circuitry turns off the switch, thus preventing the device from damage. Hysteresis is built into the thermal sense, and after the device has cooled approximately 10 degrees, the switch turns back on. The switch continues to cycle off and on until the fault is removed. The open-drain false reporting output (\overline{OC}) is asserted (active low) when an overtemperature shutdown or overcurrent occurs.

UNDERVOLTAGE LOCKOUT

A voltage sense circuit monitors the input voltage. When the input voltage is below approximately 2V, a control signal turns off the power switch.



11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
TPS2049D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2049	Samples
TPS2049DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2049	Samples
TPS2049DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2049	Samples
TPS2049DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2049	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



PACKAGE OPTION ADDENDUM

11-Apr-2013

PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions a	are nominal
-------------------	-------------

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	· · ·	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS2049DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

26-Jan-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS2049DR	SOIC	D	8	2500	340.5	338.1	20.6

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products		Applications	
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Security	www.ti.com/security
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com		
OMAP Applications Processors	www.ti.com/omap	TI E2E Community	e2e.ti.com
Wireless Connectivity	www.ti.com/wirelessconne	ectivity	

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2013, Texas Instruments Incorporated